

Finite Temperature Density Instability at High Landau Level Occupancy

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We study here the onset of charge density wave instabilities in quantum Hall systems at finite temperature for Landau level filling $\nu > 4$. Specific emphasis is placed on the role of disorder as well as an in-plane magnetic field. Beyond some critical value, disorder is observed to suppress the charge density wave melting temperature to zero. In addition, we find that a transition from perpendicular to parallel stripes (relative to the in-plane magnetic field) exists when the electron gas thickness exceeds $\approx 60\text{\AA}$. The perpendicular alignment of the stripes is in agreement with the experimental finding that the easy conduction direction is perpendicular to the in-plane field.

Recent experiments by Lilly and co-workers [1] as well as by Du and co-workers [2] have shown surprisingly that when a 2D electron gas is subjected to perpendicular magnetic fields of intermediate strength so that multiple Landau levels ($N \geq 2$) are occupied, the resultant transport properties are strongly anisotropic. Specifically, the longitudinal resistivity was found to depend on the direction of the current at sufficiently low temperature for filling factors $\nu > 4$. While the anisotropy is largest at $\nu = 9/2$ and decreases subsequently as ν is increased, the signature anisotropy is observed to persist for filling factors up to $\nu = 23/2$. This behaviour is in contrast to what is traditionally observed at high magnetic fields such that only the $N = 0$ or $N = 1$ Landau levels are occupied [3-5]. In addition, subsequent experiments have shown [6,7] that the axis along which the anisotropy is oriented can be changed by a sufficiently strong in-plane magnetic field. Further, at $\nu = 5/2$, an anisotropic state is observed only in the presence of a parallel field. This indicates that in the presence of an in-plane field, the anisotropic electronic state is lower in energy than the corresponding isotropic state at $\nu = 5/2$.

Anisotropic transport is inconsistent with a uniform electron state. As a consequence, charge density wave (CDW) formation has risen to the fore as the leading explanation of these experiments [1,2]. In principle, the ground state of a 2D electron gas is expected to be non-uniform when the magnetic field (B) is sufficiently low so that no fractional quantum Hall states are accessible but not so low that disorder destroys the gap established by the cyclotron frequency, ω_c . In this intermediate range of magnetic fields, the ground state is governed by the competition between the short-range exchange and long-range direct Coulomb interactions. Because these interactions are of opposite sign, the electron gas breaks into domains. Several years ago, Fogler, Koulakov, and Shklovskii [8] (FKS) and Moessner and Chalker [9] (MC) showed that at the Hartree-Fock level at $T = 0$, the filling in the highest Landau level oscillates between zero and unity with a well-defined period. Periodic stripe or bub-

ble phases were found to be stable as the filling in the top Landau level was varied. Recent numerical simulations [10] on small numbers of particles have also confirmed charge density wave formation for $N \geq 2$.

In this work, we focus on the role disorder and a finite in-plane magnetic field play on the CDW instability at finite temperature for $N \geq 2$. First, we include disorder in an iterative screened Hartree-Fock approach that incorporates Landau level mixing explicitly. Second, we compare our results with those of previous effective theories [9,11] for the top Landau level. We find that the results from the effective theory for the width of the stripes and the melting temperature are in good agreement with the approach used here. We then adopt the effective interaction approach to study the role of an in-plane magnetic field. The key assumption is that it is the orbital effect of the in-plane field rather than the Zeeman energy that affects the CDW instability. In addition, we find that a transition from perpendicular to parallel stripes (relative to the in-plane magnetic field) exists when the electron gas thickness exceeds $\approx 60\text{\AA}$.

The starting point for our analysis is the Hartree-Fock (HF) equation, $(H_0 + \Sigma_\sigma^{\text{HF}})\psi_{n\sigma x_0}(\mathbf{r}) = E_{n\sigma x_0}\psi_{n\sigma x_0}(\mathbf{r})$, where H_0 is the non-interacting Hamiltonian for a system of electrons in a transverse magnetic field, $\Sigma_\sigma^{\text{HF}}$ is the Hartree-Fock self-energy, $\psi_{n\sigma x_0}(\mathbf{r})$ are the single particle wavefunctions and $E_{n\sigma x_0}$ are the single particle energies. This matrix equation leads naturally to Landau-level mixing when the self energy, Σ^{HF} , is non-diagonal as is the case for an inhomogeneous system. To solve this equation, we expand the single particle wavefunctions

$$\psi_{n\sigma x_0}(\mathbf{r}) = \sum_{n'} C_{nn'}(\sigma, x_0) \phi_{n'x_0} \quad (1)$$

in terms of the Landau basis, $\phi_{nx_0}(\mathbf{r}) = \exp(-ix_0y/\ell^2)\Phi_n(x-x_0)/\sqrt{L_y}$, where Φ_n is a harmonic oscillator state centered at $x_0 = 2\pi\ell^2p/L_y$ with $p = 0, \pm 1, \dots$ and L_y is the width of the sample in the y -direction. Due to computational constraints, we limit our analysis to the configurations with translational

symmetry in one direction. Therefore we are concerned only with stripe-like instabilities. In the Landau basis, the HF equations

$$\sum_{n'} H_{nn'} C_{nn'}(\sigma, x_0) = E_{n\sigma x_0} C_{nn'}(\sigma, x_0) \quad (2)$$

reduce to a self-consistent determination of the expansion coefficients $C_{nn'}$ and $E_{n\sigma x_0}$. The matrix elements of the Hamiltonian involve a free term, $(H_0)_{nn'} = \delta_{nn'}(\hbar\omega_c(n + 1/2) - \sigma g\mu_B B/2)$, where μ_B is the Bohr magneton and g the gyromagnetic ratio as well as contributions from direct and exchange self-energy interactions:

$$\begin{aligned} \Sigma_{nn'}^H(x_0) &= \sum_{m\sigma y_0} f(E_{m\sigma y_0}) \langle \phi_{nx_0} \psi_{m\sigma y_0} | v | \phi_{n'x_0} \psi_{m\sigma y_0} \rangle \\ \Sigma_{nn'}^{\text{ex}}(\sigma x_0) &= - \sum_{my_0} f(E_{m\sigma y_0}) \langle \phi_{nx_0} \psi_{m\sigma y_0} | u | \psi_{m\sigma y_0} \phi_{n'x_0} \rangle \end{aligned}$$

with $f(E_{n\sigma y_0}) = [\exp((E_{n\sigma y_0} - \mu)/T) + 1]^{-1}$. In the direct term, the Coulomb interaction, $v(q) = 2\pi e^2/\kappa|q|$, is screened only by the semiconductor background with static dielectric constant κ , while the exchange term, $u(q) = 2\pi e^2/\kappa\epsilon(q)|q|$, is screened by the electron liquid with dielectric constant, $\epsilon(q) = 1 - (2\pi e^2/q)\chi(q)$ [12].

At the level of the random-phase approximation (RPA), the exact expressions for this polarization effect can be calculated only for a homogeneous system. To extend these results to the inhomogeneous case, we perform an average of χ over the period of the CDW. This procedure should be accurate as long as χ is slowly varying in the range of filling factors spanned by the period of the CDW. Consequently, following the result of Manolescu and Gerhardt [12], we write the inter-Landau susceptibility as

$$\begin{aligned} \chi(q) &= \frac{1}{2\pi\ell^2} \sum_{n \neq n'} \left[F_{nn'} \left(\frac{(q\ell)^2}{2} \right) \right]^2 \\ &\times \frac{1}{R} \sum_{\sigma} \sum_{x_0=1}^R \frac{f(E_{n\sigma x_0}) - f(E_{n'\sigma x_0})}{E_{n\sigma x_0} - E_{n'\sigma x_0}} \end{aligned} \quad (3)$$

where R is the number of guiding centers within a period,

$$F_{nn'}(z) = \left(\frac{n!}{n'} \right)^{\frac{1}{2}} z^{(n-n')/2} e^{-z/2} L_{n'}^{n-n'}(z) \quad (4)$$

and $L_n^m(z)$ is an associated Laguerre polynomial.

In the presence of disorder, the energy levels acquire finite width. Experimentally, the broadening parameter, Γ , has been found to scale as $\Gamma = \Gamma_0 \sqrt{B}$. Phenomenologically, this behavior can be incorporated into our scheme by using the spectral function in the form [13]

$$\rho_{\sigma}(n, y_0, \omega) = \frac{1}{\sqrt{\pi}} \frac{\hbar}{\Gamma} \exp \left[-\frac{(\hbar\omega - E_{n\sigma y_0})^2}{\Gamma^2} \right]. \quad (5)$$

As a consequence the Fermi functions $f(E_{n\sigma y_0})$ in the above equations need to be replaced by the filling factors

$$\nu_{n\sigma y_0} = \int_{-\infty}^{\infty} d\omega f(\hbar\omega) \rho_{\sigma}(n, y_0; \omega). \quad (6)$$

We solve Equations (2–3) in real space starting from a non-interacting initial guess for the energy levels. To evaluate the inhomogeneous screening, we chose a grid composed of 16 to 32 points per period of the CDW. We included as many as 10 Landau levels. The parameters used in the computation (which are specialized to GaAs) are as follows: $m^* = 0.067m_e$, $g = 0.4$, $\kappa = 12.7$, and $n = 2.4 \times 10^{11} \text{ cm}^{-2}$. With these parameters, $\hbar\omega_c = 20B$, for the cyclotron gap, $e^2/\kappa\ell = 51\sqrt{B}$, for the strength of Coulomb interaction, and $0.133B$ for bare spin splitting. Here, the energies are measured in Kelvin and magnetic field, B , in Tesla. All of the computations were performed for a fixed number of electrons, with the chemical potential, μ , being determined self-consistently.

In order to obtain the CDW versus homogeneous phase diagram, we must first determine the optimal period of the CDW. The optimal period yields the highest melting temperature for a given average filling. We find that this wavelength coincides with the period of the CDW with the lowest free energy. The results for the optimal period, λ_1 , at half filling in terms of magnetic length ℓ are shown below:

ν	4.5	5.5	6.5	7.5
λ_1	5.84	5.90	6.93	6.99
λ_2	6.13	6.19	7.18	7.22
λ_3	6.04	6.04	7.14	7.14

The error in the determined values is on the order of 1%. From the theory of FKS, it is expected that the period at half-filling, λ_3 , of the CDW should only depend on N . Indeed, we observe minor variation for different spin polarizations, and the periods we obtain are quite close to the FKS value, $\lambda_3 = 2.7\sqrt{2N+1}$. Within the same Landau level, we find however, a reduction in λ away from half-filling. For example, at filling fractions 0.2 and 0.8, the reduction is on the order of 4–5%. The values of λ_2 were obtained from an effective theory for the top Landau level [9]. These values are also in close agreement with the theoretical estimate and the results from the numerical scheme outlined above.

Shown in Fig. (1) are the melting temperatures at half filling as a function of magnetic field. The triangles represent the results for the screened Hartree-Fock approach. As mean-field estimates these values will certainly be reduced by quantum fluctuations [14] and hence set an upper bound for the temperature at which a charge instability occurs. These values do, however, conform to the experimental trend that the temperature at which the anisotropy is observed decreases as ν increases. Also shown in Fig. (1) are the melting temperatures computed using the effective theory [9] for the top Landau level.

The circles represent melting temperatures at half-filling and the asterisks to the corresponding quantity for an electron gas with root-mean-square (rms) thickness of 100Å. As is evident, all three estimates for the CDW melting temperatures are in close agreement suggesting that the approximations incurred in the effective theories are consistent. The inset in Fig. (1) shows how the disorder as measured by Γ_0 attenuates CDW formation at $\nu = 4.5$. As is evident, a critical value of the disorder, $\Gamma_0^c \approx 8.3$, exists above which the CDW phases desist. Experimentally, the disorder parameter Γ_0 can be estimated, for example, from the lowest magnetic field for which de Haas-Van Alphen oscillations are observed. In very clean samples [1], the oscillations disappear below 50 mT. Assuming that the oscillations disappear when $2\Gamma \sim \hbar\omega_c$, we estimate that $\Gamma_0 \sim 2.2[K/T^{1/2}]$. We find, that for the range of fillings studied ($\nu \leq 15/2$) the critical value $\Gamma_0^c > 2.2$.

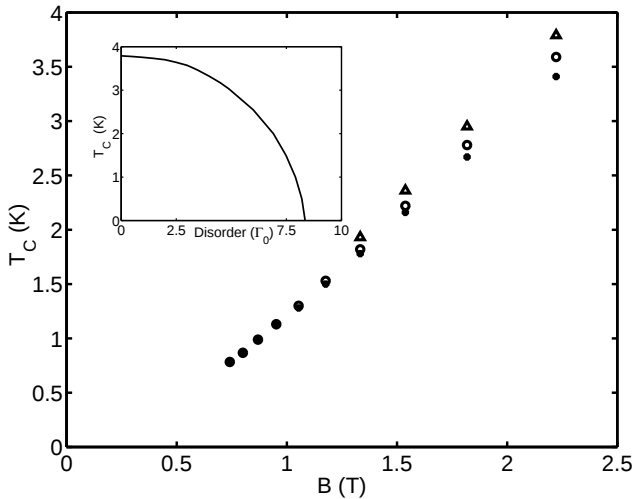


FIG. 1. Melting temperatures for CDW formation at half-filling as a function of the perpendicular magnetic field for three cases: 1) $\triangle$ represent the melting temperatures from the screened Hartree-Fock approach, 2) $\circ$ were calculated from Eq. (7) for zero thickness of the 2D layer, and 3) $*$ the same method but with an rms thickness of 100Å. The inset shows the melting temperature as a function of disorder for $\nu = 4.5$.

To understand the role of an in-plane field, we adopt the simpler approach in which the interactions in the top level are treated within an effective theory [9,8,11]. This simplification is warranted as we have seen that the results of the effective theories are in agreement with the more elaborate scheme described above. In the spirit of the work of Fukuyama, Platzman and Anderson [15], we work within an effective Ginsburg-Landau theory and write the melting temperature for a CDW in a 2D electron gas in a perpendicular magnetic field as

$$T_c = \bar{\nu}(1 - \bar{\nu})|U(\vec{Q}_0)|, \quad (7)$$

with $\bar{\nu}$ is the fractional occupancy in the top Landau

level and $U(\vec{Q}_0)$ is the effective Hartree-Fock potential evaluated at the momentum $\vec{Q}_0$ where the potential is minimized.

The primary hurdle in computing T_c is the effective Hartree-Fock potential $U(\mathbf{Q}_0)$. As the spin degrees of freedom do not couple to the stripe orientation, the spin-splitting induced by the in-plane field cannot account for the experimental observations. We focus then on the orbital effect of the in-plane field. To this end, we consider our quantum Hall system to have a finite thickness in the direction normal to the 2D plane. Due to this finite thickness, the one particle wave functions couple to the in-plane component of the magnetic field $B_{||}$. In what follows, we will neglect the contribution due to the coupling of $B_{||}$ to the electron spin. Let us consider a system of electrons moving in the $x - y$ plane in the presence of a tilted magnetic field $\mathbf{B} = (B \tan \theta, 0, B)$. We assume that the confining potential in the z direction is harmonic $V(z) = m^* \Omega^2 z^2 / 2$, with a characteristic frequency determined from the rms thickness in the z -direction, $\Omega = \hbar / 2mL_z^2$. While the actual confining potential differs from the parabolic form chosen here, the main features of the finite thickness should be correctly captured by appropriately choosing the rms width. By solving the Schrödinger equation in the gauge $\mathbf{A} = (0, -zB \tan \theta + xB, 0)$, we obtain the one-particle wave functions for this system:

$$\begin{aligned} \phi_{n x_0}(\mathbf{r}) = & \frac{1}{\sqrt{L_y}} e^{-\frac{i x_0 y}{\ell^2}} \Phi_0^+((x - x_0) \sin \tilde{\theta} + z \cos \tilde{\theta}) \\ & \times \Phi_n^{\omega_-}((x - x_0) \cos \tilde{\theta} - z \sin \tilde{\theta}) \end{aligned} \quad (8)$$

where Φ_n^{ω} is the harmonic oscillator wave function corresponding to the frequency ω and $\tilde{\theta}$ is given by $\tan \tilde{\theta} = \tan \theta \omega_c^2 / (\omega_+^2 - \omega_c^2)$. The frequencies $\omega_{\pm}$

$$\omega_{\pm}^2 = \frac{1}{2} \left(\Omega^2 + \frac{\omega_c^2}{\cos^2 \theta} \right) \pm \sqrt{\frac{1}{4} \left(\Omega^2 - \frac{\omega_c^2}{\cos^2 \theta} \right)^2 + \Omega^2 \omega_c^2 \tan^2 \theta}$$

depend on the strength and orientation of the magnetic field and on the confining potential. In the absence of $B_{||}$, ω_+ reduces to Ω and ω_- to the cyclotron frequency ω_c .

Using the one-particle states Eq. (8), we are able now to compute the matrix elements $\langle \phi_{n x_0} | e^{i \mathbf{Q} \cdot \mathbf{r}} | \phi_{m y_0} \rangle$ needed for the determination of the effective potential $U(\mathbf{Q}_0)$. Explicitly, we write the effective potential as a sum of a Hartree term

$$U_H(q_x, q_y) = \frac{e^2}{\kappa \epsilon(q_x, q_y) l_0^2} \int_{-\infty}^{\infty} \frac{dq_z}{\pi} \frac{1}{q_{||}^2 + q_z^2} [F_{nn}^{\theta}(\mathbf{q})]^2$$

and a Fock term

$$U_F(q_x, q_y) = -2\pi l_0^2 \int \frac{dk_x dk_y}{(2\pi)^2} U_H(k_x, k_y) e^{i(k_x q_y - k_y q_x) l_0^2}$$

where $F_{nn}^{\theta}(\mathbf{q})$ is the analog of Eq. (4) for the case of a tilted field and is given by

$$F_{nn'}^\theta(q_x, q_y, q_z) = \left(\frac{n!}{n'}\right)^{\frac{1}{2}} \left(\frac{\alpha^2}{2}\right)^{\frac{n-n'}{2}} e^{-\frac{\gamma^2}{4} - \frac{\alpha^2}{4}} L_{n'-n'}^{\frac{\alpha^2}{2}} \left(\frac{\alpha^2}{2}\right)$$

with

$$\begin{aligned} \gamma^2 &= (q_z \cos \tilde{\theta} + q_x \sin \tilde{\theta})^2 l_+^2 + q_y^2 \sin^2 \tilde{\theta} l_0^4 / l_+^2 \\ \alpha^2 &= (q_x \cos \tilde{\theta} - q_z \sin \tilde{\theta})^2 l_-^2 + q_y^2 \cos^2 \tilde{\theta} l_0^4 / l_-^2. \end{aligned} \quad (9)$$

The dielectric constant $\epsilon(q_x, q_y)$ is calculated in the RPA approximation (see Eq. (3)). In this case, we used the non-interacting energies $E_{n\sigma}^0 = \hbar\omega_c(n + \frac{1}{2}) - \frac{\sigma}{2}g\mu_B B$ instead of the self-consistent energies $E_{n\sigma x_0}$ and the $\mathbf{q}$ dependence enters through the angle dependent function $F_{nn'}^\theta(q_x, q_y, 0)$.

Using this method, we minimized the effective potential for two orientations of the stripes: perpendicular and parallel to the in-plane magnetic field. In general, the minimum value of the effective potential is displaced both vertically in energy and horizontally in wavevector. With extreme consistency, we observed that the wavevector for stripes oriented parallel to the in-plane field always exceeded the wavevector for those perpendicular to the stripes. This difference was not more than 4%. Our results for the change in the melting temperature (T_c) as a function of an in-plane field for an rms thickness of 100Å are shown in Fig. (2). The solid curves correspond to a parallel orientation of the stripes (with respect to the in-plane field) while the dashed curves denote the perpendicular orientation of the stripes. As is evident, the melting temperature for stripes oriented parallel to the field is consistently higher than T_c for the perpendicular orientation as ν is incremented. However, as shown in the inset, this trend reverses as the rms thickness is reduced below 65.3Å for $\nu = 6.5$. Below this thickness, the difference in melting temperature between perpendicular and parallel stripes is $O(1mK)$ for a magnetic field tilted at 45° . This temperature difference directly translates into an energy difference per electron between the two phases at low temperatures [8]. To determine which phase is preferred, we must compare the total energy difference with the temperature. As the temperature is lowered below T_c , the correlation length of the ordered charge density wave domains grows until perfect orientational order is reached at the Kosterlitz-Thouless temperature. For sufficiently large domains, even miniscule energy differences per electron can lead to orientational order and hence anisotropic transport. Hence, we predict that for thin electron gases ($\lesssim 60\text{\AA}$), the perpendicular orientation is preferred, whereas for thicker electron gases ($\gtrsim 60\text{\AA}$) parallel stripes dominate. Interestingly enough, Eisenstein [16] places the electron gas thickness at 58Å and experiments [7] identify the direction of the in-plane field as being the high resistive direction. This experimental result is consistent with our finding that perpendicular stripes are energetically favoured for thin electron gases.

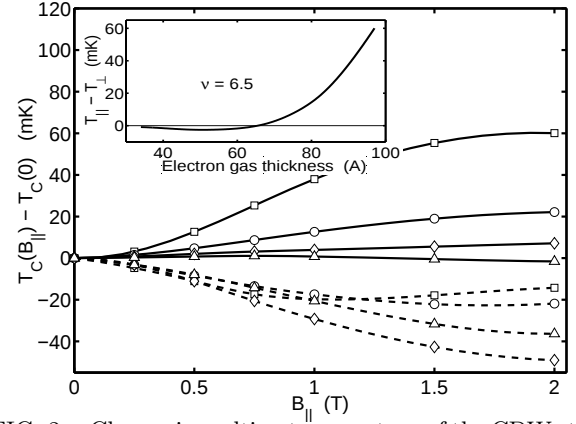


FIG. 2. Change in melting temperature of the CDW stripe phases as a result of a parallel magnetic field for an rms thickness of 100Å. The solid curves correspond to stripes oriented parallel to the field and the dashed lines to a perpendicular alignment with respect to the field. Four filling factors are shown: $\square$, $\circ$, $\diamond$, and $\triangle$ correspond to $\nu = 4.5, 5.5, 6.5$, and 7.5 , respectively. The inset shows the difference in the melting temperature between parallel and perpendicular stripes as a function of the thickness of the electron gas in Å.

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